International **ICR** Rectifier HEXEFT® POWER MOSFET PHOTOVOLTAIC RELAY

Data Sheet No. 1.042

Series PVT322A

Microelectronic Power IC Relay Dual Pole, Normally Open 0-250V, 170mA AC/DC

General Description

The PVT322A Series Photovoltaic Relay is a dualpole, normally open solid-state relay that can replace electromechanical relays in many applications. It utilizes International Rectifier's HEXFET power MOSFET as the output switch, driven by an integrated circuit photovoltaic generator of novel construction. The output switch is controlled by radiation from a GaAIAs light emitting diode (LED) which is optically isolated from the photovoltaic generator.

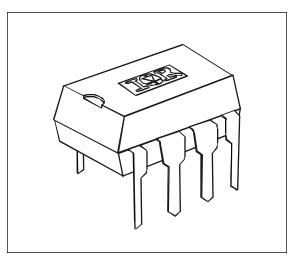
Series PVT322A Relays are packaged in an 8-pin, molded DIP package with either through-hole or surface mount (gull-wing) terminals. It is available in standard plastic shipping tubes or on tape-andreel. Please refer to Part Identification information opposite.

Applications

- On/Off Hook switch ■
- Tip and Ring Line switching
 - General switching ■

PVT322A Features

- HEXFET Power MOSFET output
 - Bounce-free operation
 - 4,000 V_{RMS} I/O isolation ■
 - Linear AC/DC operation
 - Solid-State reliability
 - UL recognition pending



Part Identification

PVT322A through-hole PVT322AS SMT PVT322AS-T SMT, T&R

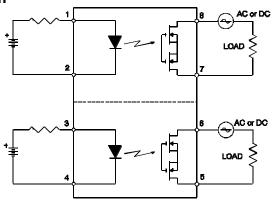
Electrical Specifications (-40°C \leq T_A \leq +85°C unless otherwise specified)

INPUT CHARACTERISTICS	Limits	Units
Minimum Control Current (See figure1)	2.0	mA
Maximum Control Current for Off-State Resistance @TA=+25°C	0.4	mA
Control Current Range (Caution: current limit input LED, see figure 5)	2.0 to 25	mA
Maximum Reverse Voltage	7.0	V

OUTPUT CHARACTERISTICS	Limits	Units
Operating Voltage Range	0 to ±250	V(DC or AC peak)
Maximum Load Current @ T _A =+40°C		
5mA Control (See figure 1) (single and dual channel operation)	170	mA
Maximum Peak Load Current (10ms maximum duration)		
(single and dual channel operation)	500	mA
Maximum On-State Resistance @T _A =+25°C		
For 50mA Pulsed load, 5mA Control (see figure 3)	8	Ω
Maximum Off-State Leakage @T _A =+25°C, ±250V (see figure 4)	1.0	μA
Maximum Turn-On Time @T _A =+25°C (see figure 6)	3.0	ms
For 50mA, 100 V _{DC} load, 5mA Control		
Maximum Turn-Off Time @T _A =+25°C (see figure 6)	0.5	ms
For 50mA, 100 V _{DC} load, 5mA Control		
Maximum Output Capacitance @ 50V _{DC}	50	pF

GENERAL CHARACTERISTICS		Limits	Units
Minimum Dielectric Strength, Input-Output		4000	V _{RMS}
Minimum Dielectric Strength, Pole-to-Pole		1000	V _{DC}
Minimum Insulation Resistance, Input-Output,	@T _A =+25°C, 50%RH, 100V _{DC}	10 ¹²	Ω
Maximum Capacitance, Input-Output		1.0	pF
Maximum Pin Soldering Temperature (10 sec	conds maximum)	+260	
Ambient Temperature Range:	Operating	-40 to +85	°C
	Storage	-40 to +100	

Connection Diagram



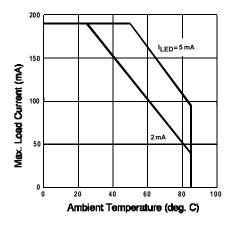


Figure 1. Typical Current Derating Curve

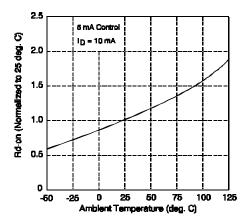


Figure 3. Typical Normalized On-Resistance

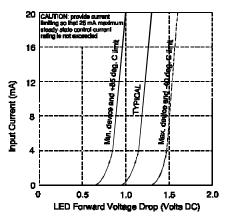


Figure 5. Input Characteristics (Current Controlled)

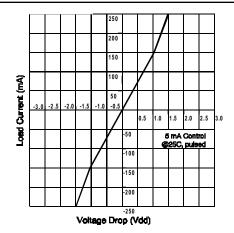


Figure 2. Linearity Characteristics

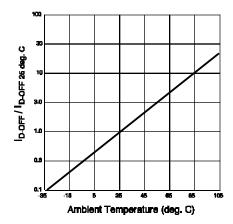


Figure 4. Typical Normalized Off-State Leakage

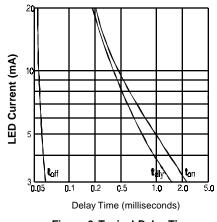
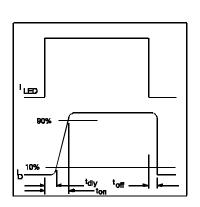


Figure 6. Typical Delay Times





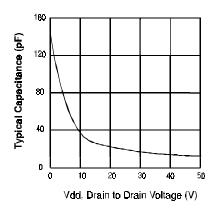
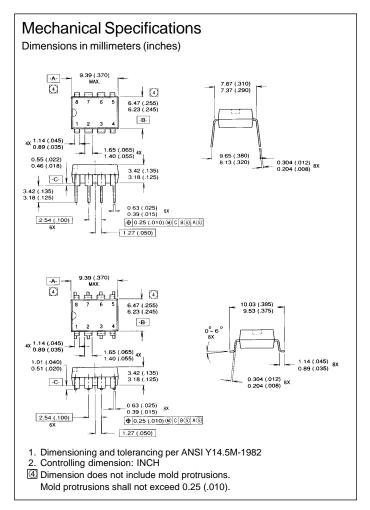


Figure 8. Typical Output Capacitance



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